

#### **Features**

- High isolation 5300 VRMS
- DC input with transistor output
- Operating temperature range 55 °C to 125 °C
- RoHS compliance
- REACH compliance
- Halogen free
- Regulatory Approvals
  - UL UL1577 (Pending Approval)
  - VDE EN60747-5-5 (Pending Approval)
  - CQC GB4943.1, GB8898 (Pending Approval)
  - IEC60065, IEC60950 (Pending Approval)

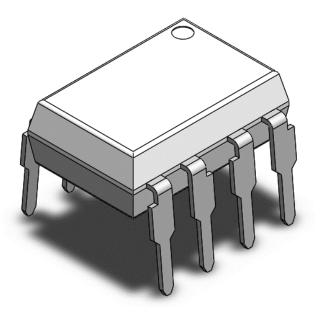
### **Description**

The CT521-2GB consists of a photo transistor optically coupled to a gallium arsenide Infrared-emitting diode in a DIP package.

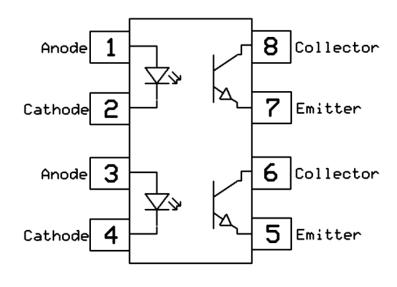
#### **Applications**

- Switch mode power supplies
- Computer peripheral interface
- Microprocessor system interface

### **Package Outline**



### **Schematic**





### Absolute Maximum Rating at 25°C

Symbol	Parameters	Ratings	Units	Notes		
Viso	Isolation voltage	5300	V <sub>RMS</sub>			
Ртот	Total power dissipation	200	mW			
Topr	Operating temperature	-55 ~ +125	°C			
Tstg	Storage temperature	-55 ~ +150	°C			
TsoL	Soldering temperature	260	°C			
Emitter						
I <sub>F</sub>	Forward current	60	mA			
I <sub>F(TRANS)</sub>	Peak transient current (≤1µs P.W,300pps)	1000	mA			
VR	Reverse voltage	6	V			
P <sub>D</sub>	Emitter power dissipation	100	mW			
Detector	Detector					
Pc	Detector power dissipation	150	mW			
B <sub>VCEO</sub>	Collector-Emitter Breakdown Voltage	80	V			
Bveco	Emitter-Collector Breakdown Voltage	7	V			
Ic	Collector Current	80	mA			



### **Electrical Characteristics** $T_A = 25$ °C (unless otherwise specified)

#### **Emitter Characteristics**

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
VF	Forward voltage	I <sub>F</sub> =10mA	-	1.25	1.4	V	
I <sub>R</sub>	Reverse Current	$V_R = 5V$	-	-	10	μΑ	
Cin	Input Capacitance	f= 1MHz	-	30	-	pF	

#### **Detector Characteristics**

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
B <sub>VCEO</sub>	Collector-Emitter Breakdown	I <sub>C</sub> = 100μA	55	-	-	V	
B <sub>VECO</sub>	Emitter-Collector Breakdown	I <sub>E</sub> = 100μA	7	-	-	V	
	Collector-Emitter Dark Current	V <sub>CE</sub> = 24V, I <sub>F</sub> =0mA	-	-	100	nA	
ICEO	Collector-Emitter Dark Current	V <sub>CE</sub> = 24V, I <sub>F</sub> =0mA,Ta = 85°C	-	-	50	μΑ	

#### **Transfer Characteristics**

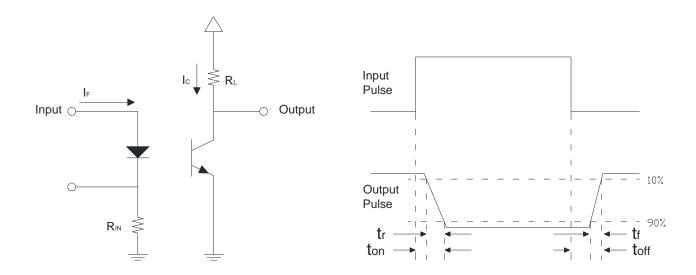
Symbol	Parameters Test Condition		Min	Тур	Max	Units	Notes
CTR	Current Transfer Ratio	I <sub>F</sub> = 5mA, V <sub>CE</sub> = 5V	100	-	600	%	
CIR		I <sub>F</sub> = 1mA, V <sub>CE</sub> = 0.4V	30	-	-	%	
	Collector-Emitter Saturation	1 4 m A 1 0 2 m A	-		0.4	V	
V <sub>CE</sub> (SAT)	Voltage	I <sub>F</sub> = 1mA, I <sub>C</sub> = 0.2mA		-	0.4		
Rio	Isolation Resistance	V <sub>IO</sub> = 500V <sub>DC</sub>	5x10 <sup>10</sup>	-	-	Ω	
C <sub>IO</sub>	Isolation Capacitance	f= 1MHz	-	0.25	1	pF	

### **Switching Characteristics**

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
t <sub>r</sub>	Rise Time		-		16	0	
t <sub>f</sub>	Fall Time	I <sub>C</sub> = 2mA, V <sub>CE</sub> = 2V	-		16	μS	
t <sub>on</sub>	Turn-on time	n time R <sub>L</sub> = 100Ω			20	0	
t <sub>off</sub>	Turn-off time				20	μS	



### **Test Circuit**

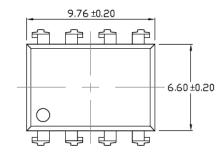


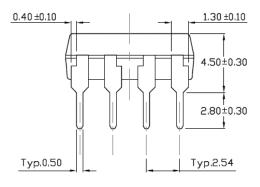
**Figure 12: Switching Time Test Circuits** 

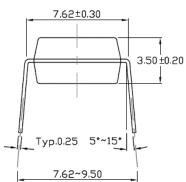


### Package Dimension Dimensions in mm unless otherwise stated

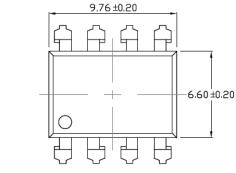
### Standard DIP – Through Hole

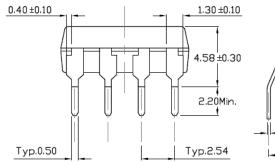


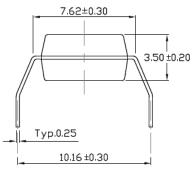




### Gullwing (400mil) Lead Forming – Through Hole (M Type)

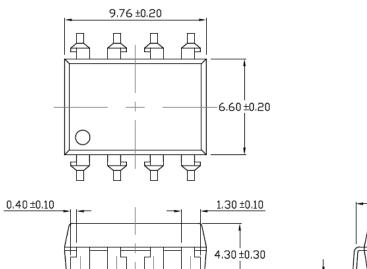


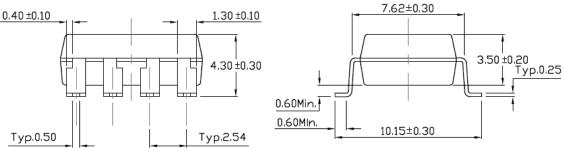




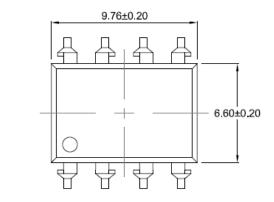


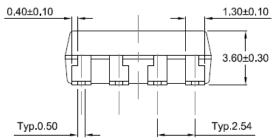
### **Surface Mount Lead Forming (S Type)**

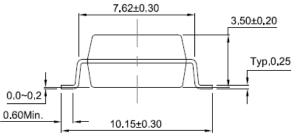




### **Surface Mount (Low Profile) Lead Forming (SL Type)**

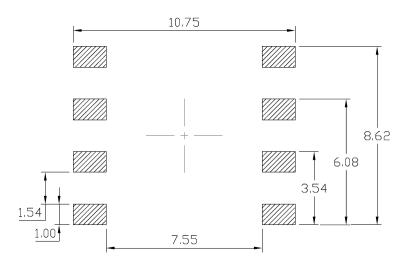




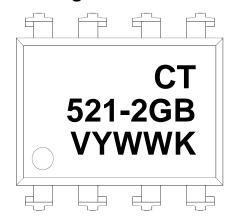




### Recommended Solder Mask Dimensions in mm unless otherwise stated



### **Marking Information**



#### Note:

CT : Denotes "CT Micro"

521-2 : Part Number GB : CTR Rank

V : VDE Safety Option ( V or none)

Y : Fiscal Year WW : Work Week

K : Manufacturing Code



### **Ordering Information**

## CT521-2GB(V)(W)(Y)

CT : Denotes "CT Micro"

521-2 : Part Number GB : CTR Rank

V : VDE Safety Option( V or none)

W : Lead form option (S, SL, M or none)Y : Tape and reel option (T1, T2 or none)

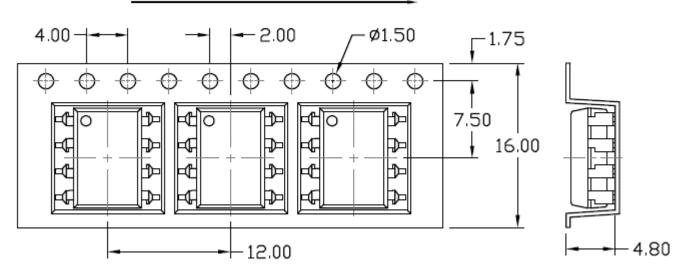
Option	Description	Quantity
None	Standard 8 Pin Dip	40 Units/Tube
M	Gullwing (400mil) Lead Forming	40 Units/Tube
S(T1)	Surface Mount Lead Forming – With Option 1 Taping	1000 Units/Reel
S(T2)	Surface Mount Lead Forming – With Option 2 Taping	1000 Units/Reel
SL(T1)	Surface Mount (Low Profile) Lead Forming– With Option 1 Taping	1000 Units/Reel
SL(T2)	Surface Mount (Low Profile) Lead Forming– With Option 2 Taping	1000 Units/Reel



### Carrier Tape Specifications Dimensions in mm unless otherwise stated

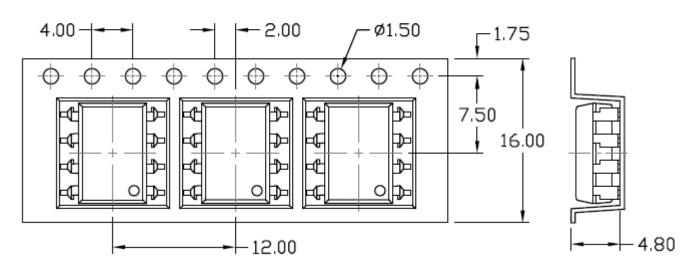
### Option S(T1) & SL(T1)

# Input Direction



### Option S(T2) & SL(T2)

# Input Direction





### Wave soldering (JEDEC22A111 compliant)

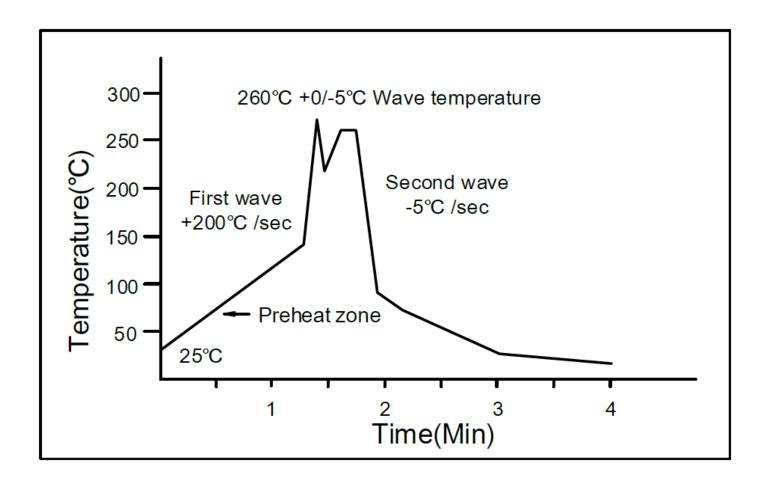
One time soldering is recommended within the condition of temperature.

Temperature: 260+0/-5°C.

Time: 10 sec.

Preheat temperature:25 to 140°C.

Preheat time: 30 to 80 sec.



### Hand soldering by soldering iron

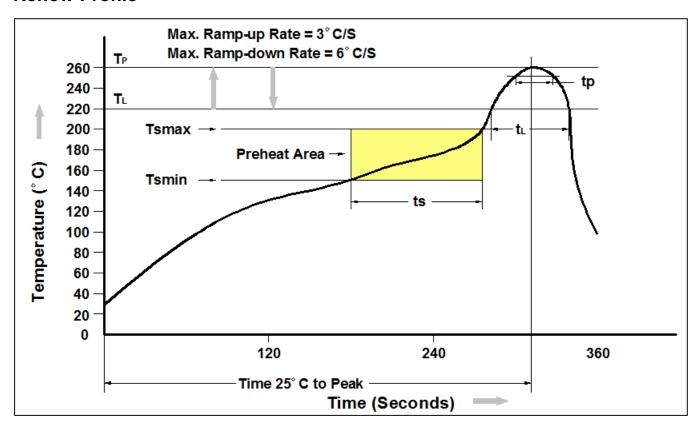
Allow single lead soldering in every single process.

One time soldering is recommended. Temperature: 350+0/-5°C

Time: 3 sec max.



#### **Reflow Profile**



Profile Feature	Pb-Free Assembly Profile			
Temperature Min. (Tsmin)	150°C			
Temperature Max. (Tsmax)	200°C			
Time (ts) from (Tsmin to Tsmax)	60-120 seconds			
Ramp-up Rate (t∟ to t⊳)	3°C/second max.			
Liquidous Temperature (T <sub>L</sub> )	217°C			
Time (t <sub>L</sub> ) Maintained Above (T <sub>L</sub> )	60 – 150 seconds			
Peak Body Package Temperature	260°C +0°C / -5°C			
Time (t <sub>P</sub> ) within 5°C of 260°C	30 seconds			
Ramp-down Rate (T <sub>P</sub> to T <sub>L</sub> )	6°C/second max			
Time 25°C to Peak Temperature	8 minutes max.			



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